# 1/4 B.Tech - SECOND SEMESTER

EC2T4	<b>Electronic Devices and Circuits</b>	Credits: 4
Lecture : 4 periods/week Tutorial: 1 period /week	In Semeste	nternal assessment: 30 marks er end examination: 70 marks
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#### **Course Objectives:**

- To study in detail about construction of several electronic devices
- To analyse the characteristics of various electronic devices and circuits
- To get familiarize in biasing and stabilization concepts

## UNIT-I

**Junction Diode Characteristics :** Open circuited P N Junction, Forward and Reverse Bias, Current components in PN Diode, Diode Equation, Volt-Amper Characteristic, Temperature Dependence on V - I characteristic, Step Graded Junction, Diffusion Capacitance and Diode Resistance (Static and Dynamic), Energy Band Diagram of PN Diode,

# UNIT-II

## Special Diodes

Avalanche and Zener Break Down, Zener Characterisitics, Tunnel Diode, Characteristics with the help of Energy Band Diagrams, Varactor Diode.

## UNIT-III

## **Rectifiers and Filters**

Halfwave Rectifier, Full wave and Bridge Rectifier, derivation of Ripple factor, Form factor, peak factor, efficiency of Half wave, full wave and Bridge rectifiers. Filters – C, L-section, LC and CLC filters, Comparison of filters.

## **UNIT-IV**

## **Opto-Electronic Devices**

Introduction to optical devices, Photo resister- construction, characteristics, applications, Photo diode- construction, characteristics, applications, LED - construction, characteristics, applications, LCD, comparison between LED and LCD

## UNIT-V

#### Transistors :

Junction transistor, Transistor current components, Transistor as an amplifier, Characteristics of Transistor in Common Base and Common Emitter Configurations, Analytical expressions for Transistor Characteristics, Punch Through/ Reach Through, Typical transistor junction voltage values, Photo Transistor,

## UNIT-VI

**Transistor Biasing and Thermal Stabilization :** Operating point, Basic Stability, Collector to Base Bias, Self Bias Amplifiers, Stabilization against variations in  $V_{BE}$ , and  $\beta$  for the self bias circuit, Stabilization factors, (S, S', S''), Bias Compensation, Thermistor and Sensitor compensation, Compensation against variation in  $V_{BE}$ , I<sub>co</sub>, Thermal runaway, Thermal stability

#### UNIT-VII Field Effect Transistors:

JFET characteristics (Qualitative and Quantitative discussion), MOSFET characteristics (Enhancement and depletion mode), Symbols of MOSFET, UJT and their characteristics,

# **UNIT-VIII**

FET Biasing: Introduction, Fixed Biasing, Self Bias, Voltage divider bias and related problems.

# Learning resources

# **Text books:**

- 1. Electronic Devices and Circuits J.Milliman, C.C Halkias, Tata Mc-Graw Hill
- 2. Integrated electronics J.Milliman, C.C Halkias, Tata Mc-Graw Hill
- 3. Electronic Devices and Circuits Theory, 8/e Boyelstad, Pearson Education, September 2011.

## **References:**

- 1. Thomas L. Floyd, "Electronic Devices", Pearson, 7<sup>th</sup> edition.
- 2. David A.Bell, "Electronic Devices and Circuits", Oxford, 5<sup>th</sup> edition.
- 3. Electronic Devices and Circuits by S.Salivahanan, Kumar, Vallavaraj, TATA McGraw Hill, Second Edition